

1 N 3920		Si-Di	=1N3919: 1500V	32a	DO-4	-
1 N 3921		Si-Di	=1N3919: 2000V	32a	DO-4	-
1 N 3922		Si-Di	=1N3919: 2500V	32a	DO-4	-
1 N 3923		Si-Di	=1N3919: 3000V	32a	DO-4	-
1 N 3924	USA	Si-Di	P Rr, 1000V, 10A(Tc=100°), Uf<2V(10A)	32a	DO-4	BYX 42/1200, BYX 98/1200
1 N 3925		Si-Di	=1N3924: 1500V	32a	DO-4	-
1 N 3926		Si-Di	=1N3924: 2000V	32a	DO-4	-
1 N 3927		Si-Di	=1N3924: 2500V	32a	DO-4	-
1 N 3928		Si-Di	=1N3924: 3000V	32a	DO-4	-
1 N 3929	USA	Si-Di	Rr, 1000V, 1A, Uf<2V(1A)	34a	DO-13	BY 127, BY 133, BY 227, 1N4007, ++
1 N 3930		Si-Di	=1N3929: 1500V	34a	DO-13	-
1 N 3931		Si-Di	=1N3929: 2000V	34a	DO-13	BY 269, DM 513, EM 516, GP 10W
1 N 3932		Si-Di	=1N3929: 2500V	34a	DO-13	-
1 N 3933		Si-Di	=1N3929: 3000V	34a	DO-13	-
1 N 3934	USA	Si-Di	P Rr, 1200V, 10A(Tc=25°), Uf<2V(10A)	32a	DO-4	BYX 42/1200, BYX 98/1200
1 N 3935	Spe	Trigger-Di	Ub=26...34V, Ib<15µA, Ih<45mA, Itsm=10A	31a	DO-7	-
1 N 3936	Spe	Trigger-Di	Ub=16...24V, Ib<0,125mA, Ih<11mA, Itsm=10A	31a	DO-7	-
1 N 3937	Itt	Trigger-Di	Ub=90...110V, Ib<0,125mA, Ih<6mA, Itsm=10A	31a	DO-7	-
1 N 3938	USA,Tho	Si-Di	Rr, contr.av., 200V, 2A, Uf<1,1V(2A)	34a	DO-13	BYW 52...56, 1N5060...62
1 N 3939		Si-Di	=1N3938: 400V	34a	DO-13	BYW 53...56, 1N5060...62
1 N 3940		Si-Di	=1N3938: 600V	34a	DO-13	BYW 54...56, 1N5061...62
1 N 3941		Si-Di	=1N3938: 800V	34a	DO-13	BYW 55...56, 1N5062
1 N 3942		Si-Di	=1N3938: 1000V	34a	DO-13	BYW 56
1 N 3943	Sol	Z-Di	2,5V, 0,75W	34a	DO-13	-
1 N 3944	USA	Ge-Di	S, 15V, <12ns	31a	DO-7	AAZ 48, 1N995
1 N 3945	Gen,Trw	Si-Di	VHF Tuning	31a	DO-14	-
1 N 3946	Gen,Trw	Si-Di	VHF Tuning	31a	DO-14	-
1 N 3947	Gen,Trw	Si-Di	VHF Tuning	31a	DO-14	-
1 N 3948		Si-Di	Tunnel-Di			
1 N 3949	USA,Sie	Z-Di	20V, 5%, 10W(Tc=25°)	32a	DO-4	BZX98/C20, BZY93/C20, ZX20, 1N2984, ++
1 N 3950	USA	Z-Di	20V, 5%, 1,5W	2c	TO-39	-
1 N 3951	USA	Z-Di	25V, 5%, 1,5W	2c	TO-39	-
1 N 3952	Sem	Si-Di	Rr, 130V, 0,2A	31a	DO-7	BA 189...190, BAY 20...21, BAY 45...46, ++
1 N 3953	Idc,Sem	Ge-Di	S, 40V, <300ns	31a	DO-7	AAZ 28, 1N631, 1N633
1 N 3954	Idc,Msc,Sem	Si-Di	SS, 50V, <4ns	31a	DO-7	BAW 62, BAX 95, 1N4148...49, 1N4446...49, ++
1 N 3955	old	Si-Di	P Rr, 100V, 70A(Tc=150°), Uf<1,3V(70A)	32	=DO-5	-
1 N 3956	Idc,Sem	Si-Di	SS, 30V, 2ns	31a	DO-7	BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 3957(GP)	USA,Sie	Si-Di	=1N3611: 1000V	31a	DO-41	BY 127, BY 133, BY 227, 1N4007, ++
1 N 3958(C)	USA	Si-Di	P Rr, 100V, 3,5A, Uf<1,3V(3,5A), <3µs(C: 1µs)	32a	DO-4	BYX 38/300, BYX 39/600
1 N 3959(C)		Si-Di	=1N3958: 200V	32a	DO-4	BYX 38/300, BYX 39/600
1 N 3960(C)		Si-Di	=1N3958: 300V	32a	DO-4	BYX 38/300, BYX 39/600
1 N 3961(C)		Si-Di	=1N3958: 400V	32a	DO-4	BYX 38/600, BYX 39/600
1 N 3962(C)		Si-Di	=1N3958: 500V	32a	DO-4	BYX 38/600, BYX 39/600
1 N 3963(C)		Si-Di	=1N3958: 600V	32a	DO-4	BYX 38/600, BYX 39/600
1 N 3964	USA	Si-Di	P Rr, contr.av., 200V, 22A(Tc=120°), Uf<0,6(26A)	32a	DO-4	BYX 25/600
1 N 3965		Si-Di	=1N3964: 400V	32a	DO-4	BYX 25/600
1 N 3966		Si-Di	=1N3964: 600V	32a	DO-4	BYX 25/600
1 N 3967		Si-Di	=1N3964: 800V	32a	DO-4	BYX 25/800
1 N 3968	USA	Si-Di	P Rr, contr.av., 200V, 50A(Tc=120°), Uf<0,6V(60A)	32a	DO-5	-
1 N 3969		Si-Di	=1N3968: 400V	32a	DO-5	-
1 N 3970		Si-Di	=1N3968: 600V	32a	DO-5	-
1 N 3971		Si-Di	=1N3968: 800V	32a	DO-5	-
1 N 3972	USA	Si-Di	P Rr, contr.av., 200V, 104A(Tc=120°), Uf<0,6V(150A)	73a	DO-8	-
1 N 3973		Si-Di	=1N3972: 400V	73a	DO-8	-
1 N 3974		Si-Di	=1N3972: 600V	73a	DO-8	-
1 N 3975		Si-Di	=1N3972: 800V	73a	DO-8	-
1 N 3976	USA	Si-Di	P Rr, contr.av., 200V, 250A(Tc=120°), Uf<0,6V(250A)	73a	DO-9	-
1 N 3977		Si-Di	=1N3976: 400V	73a	DO-9	-
1 N 3978		Si-Di	=1N3976: 600V	73a	DO-9	-
1 N 3979		Si-Di	=1N3976: 800V	73a	DO-9	-
1 N 3981	USA	Si-Di	Rr, Uni, 200V, 3A, Uf<1V(0,9A)	31a	DO-35	BY 251...255, BYW 17/200, 1N5402...08, ++
1 N 3982		Si-Di	=1N3981: 400V	31a	DO-35	BY 252...255, BYW 17/400, 1N5404...08, ++
1 N 3983		Si-Di	=1N3981: 600V	31a	DO-35	BY 253...255, BYW 17/400, 1N5406...08, ++
1 N 3984	USA,Sie	Z-Di	5,5V, 5%, 10W(Tc=25°)	32a	DO-4	BZX98/C5V6, BZY93/C5V6, ZX5,6, 1N3997, ++
1 N 3985		Z-Di	=1N3984: 6V	32a	DO-4	BZX98/C6V2, BZY93/C6V2, ZX6,2, 1N3998, ++
1 N 3986		Z-Di	=1N3984: 6,2V	32a	DO-4	BZX98/C6V2, BZY93/C6V2, ZX6,2, 1N3998, ++
1 N 3987	USA,Tho	Si-Di	P Rr, 700V, 6A(Tc=150°), Uf<1,2V(5A)	32a	DO-4	BYX 38/900, BYX 39/800
1 N 3988		Si-Di	=1N3987: 800V	32a	DO-4	BYX 38/900, BYX 39/800
1 N 3989		Si-Di	=1N3987: 900V	32a	DO-4	BYX 38/900, BYX 39/1000
1 N 3990		Si-Di	=1N3987: 1000V	32a	DO-4	BYX 38/1200, BYX 39/1000
1 N 3987R...3990R		Si-Di	=1N3987...3990:	32b	DO-4	BYX 38/...R, BYX 39/...R
1 N 3991	Idc,Sem	Ge-Di	Uni, 35V	31a	DO-7	AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 3992	Edl,Sem	Si-Di	KV-Rr, 4kV, Uf<5V(0,25A)	31a	(10x4x4mm)	GP 02-40, MR 250-4, 1N1734A
1 N 3993	USA,Mot,Sie	Z-Di	3,9V, 10%, 10W(Tc=55°)	32a	DO-4	BZX98/..., BZY93/..., ZL..., ZX...
1 N 3994		Z-Di	=1N3993: 4,3V	32a	DO-4	-
1 N 3995		Z-Di	=1N3993: 4,7V	32a	DO-4	-
1 N 3996		Z-Di	=1N3993: 5,1V	32a	DO-4	-
1 N 3997		Z-Di	=1N3993: 5,6V	32a	DO-4	-
1 N 3998		Z-Di	=1N3993: 6,2V	32a	DO-4	-
1 N 3999		Z-Di	=1N3993: 6,8V	32a	DO-4	-
1 N 4000		Z-Di	=1N3993: 7,5V	32a	DO-4	-
1 N 3993A...4000A		Z-Di	=1N3993...4000: 5%	32a	DO-4	-
1N 4001(D,G,K,P,S)	USA,EUR,JAP	Si-Di	Rr, Uni, 50V, 1A, Uf<1,1V(1A) D: SOD-81, G: SOD-57, K,P: SOD-22, S: DO-41	31a	SOD-22	1N4007 31a BY 126...127, BY 133...135, 1N5614...22, ++
1 N 4002(D,G,P,S)		Si-Di	=1N4001: 100V	31a	SOD-22	1N4007 31a BY 126...127, BY 133...135, 1N5614...22, ++
1 N 4003(D,G,P,S)		Si-Di	=1N4001: 200V	31a	SOD-22	1N4007 31a BY 126...127, BY 133...134, 1N5616...22, ++
1 N 4004(D,G,P,S)		Si-Di	=1N4001: 400V	31a	SOD-22	1N4007 31a BY 126...127, BY 133...134, 1N5616...22, ++
1 N 4005(D,G,P,S)		Si-Di	=1N4001: 600V	31a	SOD-22	1N4007 31a BY 126...127, BY 133...134, 1N5618...22, ++
1 N 4006(D,G,P,S)		Si-Di	=1N4001: 800V	31a	SOD-22	1N4007 31a BY 127, BY 133, BY 227, 1N5620...22, ++
1 N 4007(D,G,P,S)		Si-Di	=1N4001: 1000V	31a	SOD-22	1N4007 31a BY 127, BY 133, BY 227, 1N5622, ++
1 N 4007 KH		Si-Di	=1N4001: 1600V	31a	SOD-22	DM 513, DM 516, EM 516, GP 10Y
1 N 4007 KS		Si-Di	=1N4001: 1250V	31a	SOD-22	BY 133, BYX 95, EM 513, GP 10V, ++
1 N 4008	USA	Ge-Di	S, 12V, 0,1A, <70ns	31a	DO-7	AAZ 18